

High speed rectifiers

FEATURES

- > 175 °C maximum junction temperature
- Extremely fast switching independent with temperature
- Positive temperature coefficient for safe operation

Anti-Parallel 1200V 2X56A, Silicon Carbide Schottky

- No reverse recovery
- Pb-free finished; RoHS compliant

MAXIMUM RATINGS (per Diode)

Parameter	Symbol	Value	Units		
Repetitive peak reverse voltage	V _{RRM}	1200	V		
DC forward current T _c = 120 °C	I _{F(AV)}	56			
Surge non-repetitive forward current, half sine wave $T_C = 25 \circ C$, $t_p = 8.3 ms$	I _{FSM}	284	A		
Operating junction and storage temperature range	Tj, Tstg	-55 to 175	°C		

Thermal and Isolation Characteristics

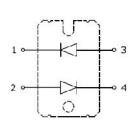
Parameter	Symbol	Max. Value	Units
Characteristics			
Thermal resistance, junction to case, per Diode	R _{thJC}	0.36	°C/W
Isolation voltage, RMS (measured between terminals and mounting base, 50-60 Hz, for 1-3 seconds)	V _{iso}	3000	V

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Diode in Isolated SOT227 Package

PRELIMINARY DATASHEET









IQID2X56SC120C3

Electrical Characteristics, at $T_j = 25$ °C, unless otherwise specified

Parameter	Symbol	Value			11
		Min.	Тур.	Max.	Unit
Static Characteristics					
Reverse leakage current $V_R = 1200V$ $V_R = 1200V$, $T_i = 150^{\circ}C$	I _R	-	-	1 1.5	mA
Forward voltage drop $I_F = 56A$ $I_F = 56A$, $T_j = 175 \circ C$	V _F	-	1.70 2.75	2.0	v
Dynamic Characteristics					
Total capacitive charge V _R =600V, I _F =56A, di/dt=100A/µs	Qc	-	64	-	nC

Figure 1 – Typical Forward voltage drop vs forward current

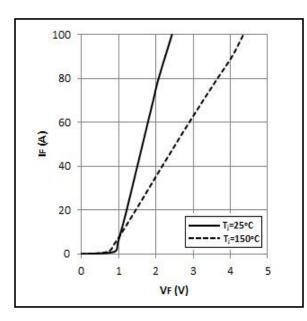
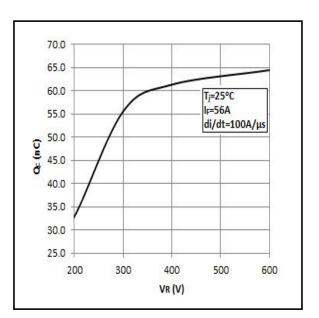


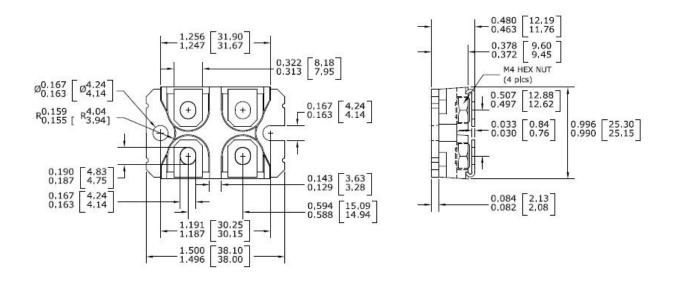
Figure 2 – Capacitive charge vs Reverse voltage







Package Outline Drawing



Disclaimer

These specifications may not be considered as a guarantee of components characteristics. Components have to be tested depending on intended application as adjustments may be necessary. The use of **iQXPRZ Power Inc.** components in life support appliances and systems are subject to written approval of **iQXPRZ Power Inc.**

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Website: <u>www.iqxprzpower.com</u> Telefax +632 837 1538